Discrete IGBTs Silicon N-Channel IGBT

# GT20J341

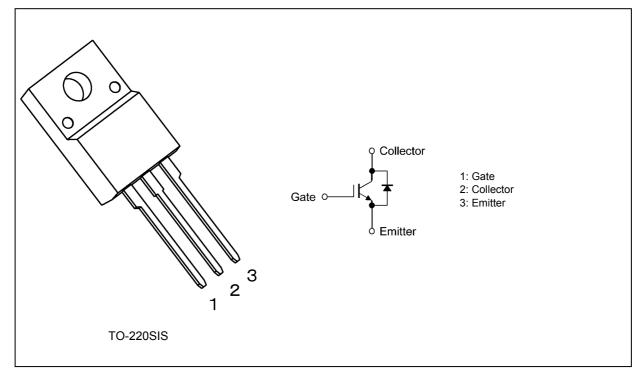
### 1. Applications

Motor Drivers

#### 2. Features

- (1) Sixth generation
- (2) Low saturation voltage:  $V_{CE(sat)} = 1.5$  V (typ.) ( $I_C = 20$  A)
- (3) FRD included between emitter and collector

#### 3. Packaging and Internal Circuit



#### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ , unless otherwise specified)

Characteristics				Rating	Unit
Collector-emitter voltage			V <sub>CES</sub>	600	V
Gate-emitter voltage			V <sub>GES</sub>	±25	
Collector current (DC)	(T <sub>c</sub> = 25°C)		Ι <sub>C</sub>	20	Α
Collector current (DC)	(T <sub>c</sub> = 100°C)		Ι <sub>C</sub>	11	
Collector current (pulsed)			I <sub>CP</sub>	80	
Diode forward current (DC)	(T <sub>c</sub> = 25°C)		I <sub>F</sub>	20	
Diode forward current (DC)	(T <sub>c</sub> = 100°C)		l <sub>F</sub>	9	
Short circuit withstand time		(Note 1)	t <sub>sc</sub>	5	μS
Collector power dissipation	(T <sub>c</sub> = 25°C)		P <sub>C</sub>	45	W
Junction temperature			Tj	150	°C
Storage temperature			T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

In general, loss of IGBT increases more when it has positive temperature coefficient and gets higher temperature.

In case that the temperature rise due to loss of IGBT exceeds the heat release capacity of a device, it leads to thermorunaway and results in destruction.

Therefore, please design heat release of a device with due consideration to the temperature rise of IGBT. Note 1:  $V_{CC}$  = 300 V,  $V_{GG}$  = +15 V/0 V,  $T_i \le 125^{\circ}C$ 

#### 5. Thermal Characteristics

Characteristics		Мах	Unit
Junction-to-case thermal resistance (IGBT)		2.78	°C/W
Junction-to-case thermal resistance (diode)		4.23	

#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (T<sub>a</sub> = 25°C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GES</sub>	$V_{GE}$ = ±25 V, $V_{CE}$ = 0 V	_	_	±100	nA
Collector cut-off current	I <sub>CES</sub>	V <sub>CE</sub> = 600 V, V <sub>GE</sub> = 0 V	_	_	100	μA
Gate-emitter cut-off voltage	V <sub>GE(OFF)</sub>	$I_{C}$ = 2 mA, $V_{CE}$ = 5 V	3.5	5.5	6.5	V
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C}$ = 20 A, $V_{GE}$ = 15 V, $T_{c}$ = 25°C		1.5	2.0	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{C}$ = 20 A, $V_{GE}$ = 15 V, $T_{c}$ = 125°C	_	1.8	—	
Diode forward voltage	V <sub>F</sub>	$I_F$ = 20 A, $V_{GE}$ = 0 V, $T_c$ = 25°C		1.5	2.1	
Diode forward voltage	V <sub>F</sub>	$I_F$ = 20 A, $V_{GE}$ = 0 V, $T_c$ = 125°C	_	1.3	_	

### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ , unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	Cies	V <sub>CE</sub> = 10 V, V <sub>GE</sub> = 0 V, f = 100 kHz		1790	—	pF
Switching time (turn-on delay time)	t <sub>d(on)</sub>	Inductive load	_	0.06	_	μS
Switching time (rise time)	tr	$V_{CC} = 300 \text{ V}, \text{ I}_{C} = 20 \text{ A},$		0.04	_	
Switching time (turn-on time)	t <sub>on</sub>	$V_{GG} = +15 \text{ V/0 V, } R_{G} = 33 \Omega$ $T_{c} = 25^{\circ}\text{C},$ See Fig. 6.2.1, 6.2.2, 6.2.3		0.16	_	
Switching time (turn-off delay time)	t <sub>d(off)</sub>		_	0.24	_	
Switching time (fall time)	t <sub>f</sub>	]		0.05	_	
Switching time (turn-off time)	t <sub>off</sub>	]		0.35	_	
Switching loss (turn-on switching loss)	Eon		_	0.5	_	mJ
Switching loss (turn-off switching loss)	E <sub>off</sub>	]		0.4	_	
Switching time (turn-on delay time)	t <sub>d(on)</sub>	Inductive load		0.07	—	μS
Switching time (rise time)	tr			0.04	—	
Switching time (turn-on time)	t <sub>on</sub>			0.2	—	
Switching time (turn-off delay time)	t <sub>d(off)</sub>			0.23	_	
Switching time (fall time)	t <sub>f</sub>			0.09	_	
Switching time (turn-off time)	t <sub>off</sub>	]		0.37	_	
Switching loss (turn-on switching loss)	Eon	]	_	0.6	_	mJ
Switching loss (turn-off switching loss)	E <sub>off</sub>	]		0.5	—	
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = 20 A, di/dt = -100 A/μs		90	_	ns

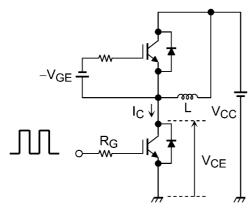


Fig. 6.2.1 Test Circuit of Switching Time

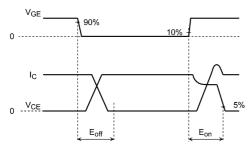


Fig. 6.2.3 Timing Chart of Switching Loss

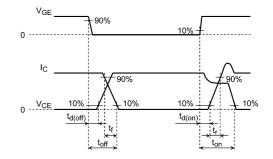
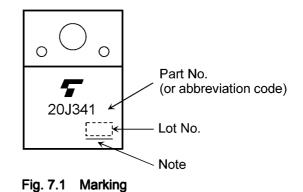


Fig. 6.2.2 Timing Chart of Switching Time

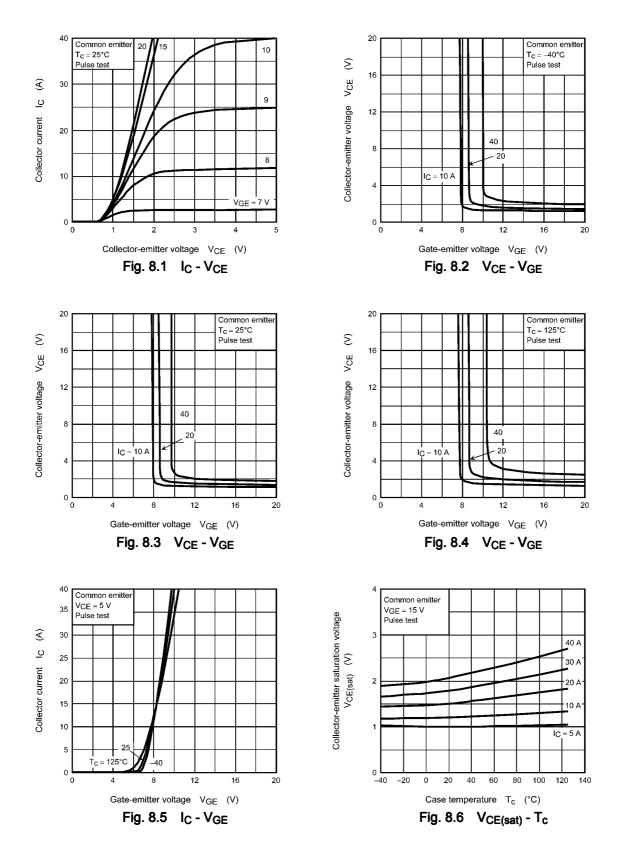
### 7. Marking (Note)

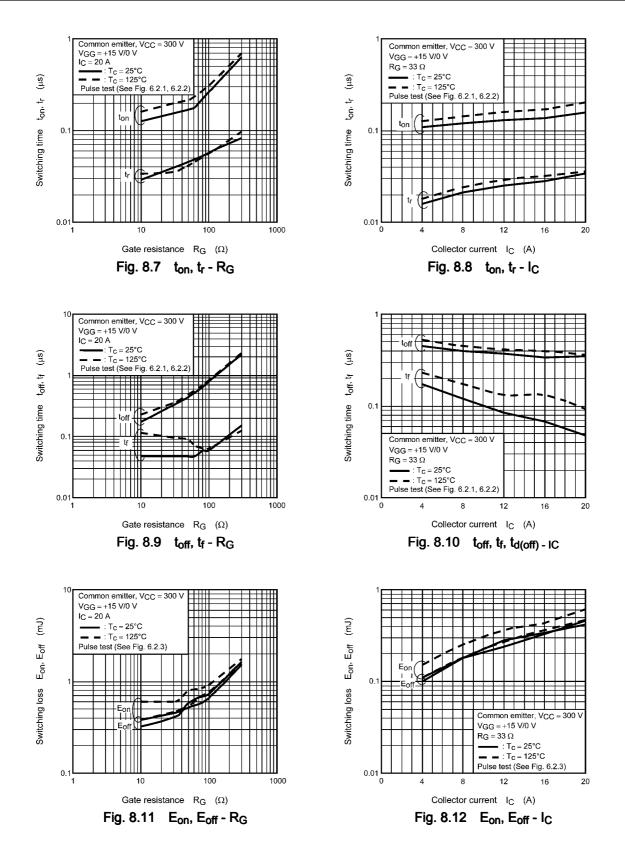


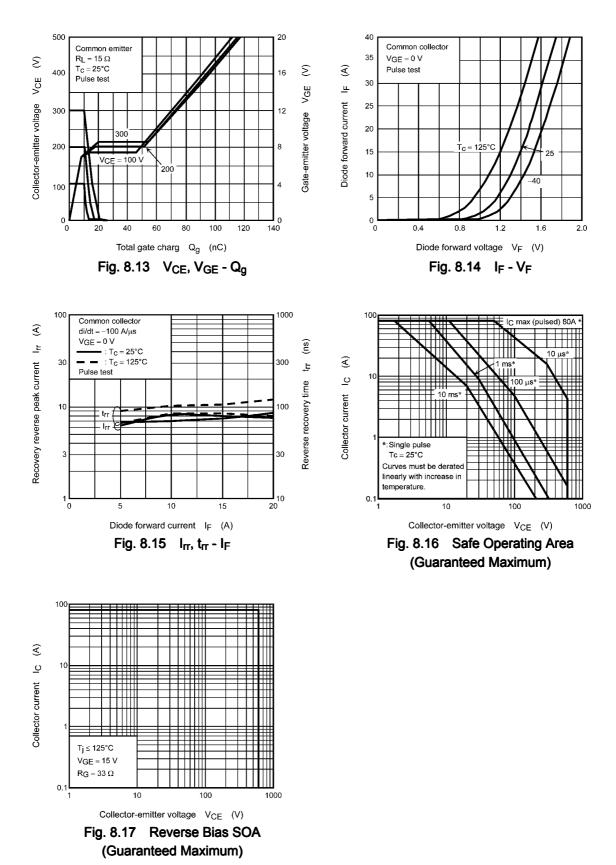
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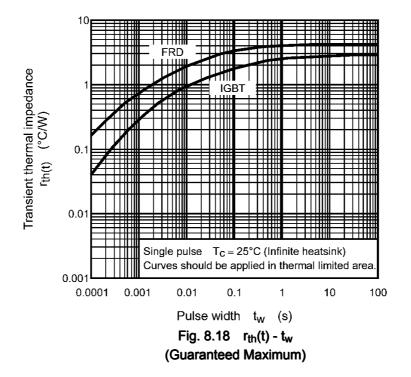
Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

### 8. Characteristics Curves (Note)







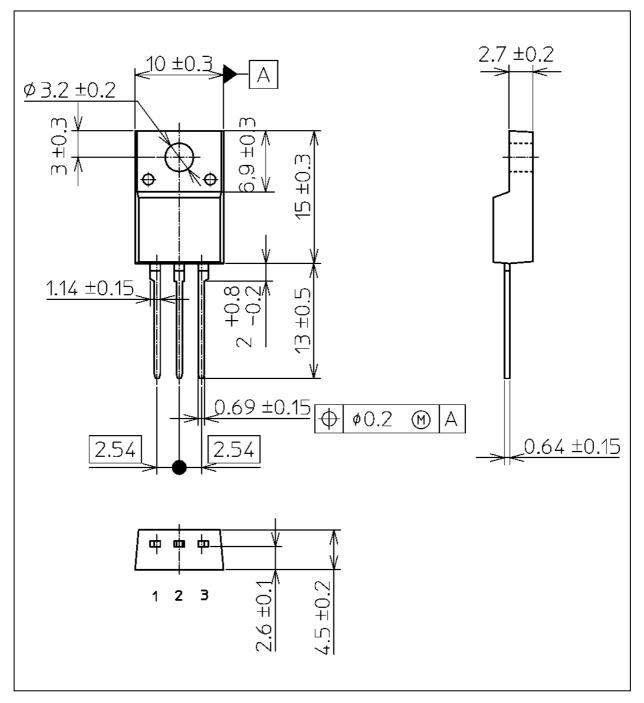


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### Package Dimensions

GT20J341

Unit: mm



Weight: 1.7 g (typ.)

	Package Name(s)
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	

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